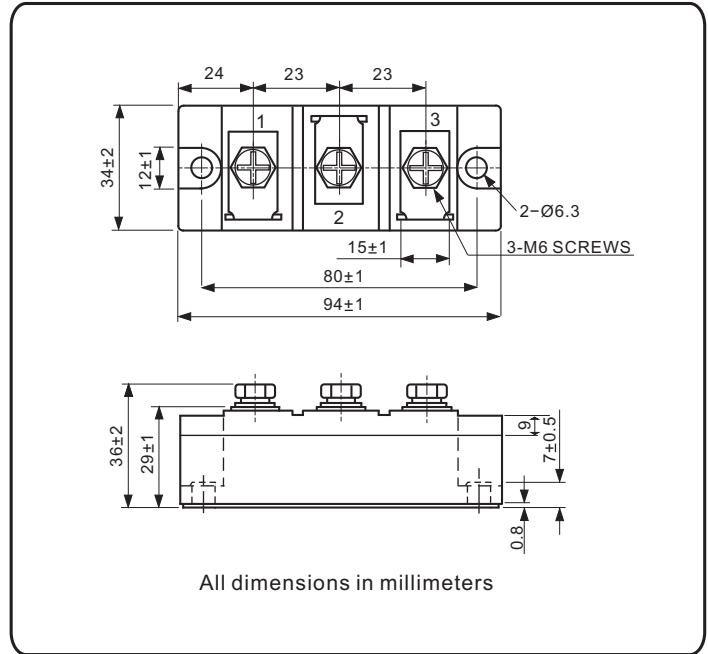


## Standard Recovery Diodes, 200 A (INT-A-PAK Power Modules)



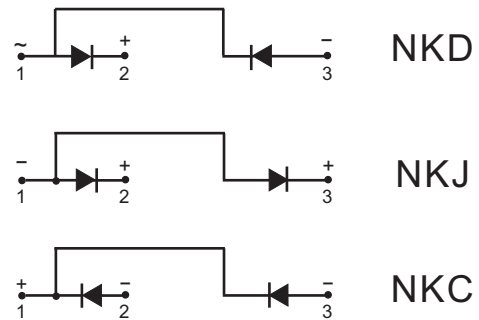
### FEATURES

- High voltage
- Electrically isolated by DBC ceramic ( $Al_2O_3$ )
- 3000  $V_{RMS}$  isolating voltage
- Industrial standard package
- High surge capability
- Modules uses high voltage power diodes in four basic configurations
- Simple mounting
- UL approved file E320098
- Compliant to RoHS
- Designed and qualified for multiple level



### APPLICATIONS

- DC motor control and drives
- Battery charges
- Welders
- Power converters



PRODUCT SUMMARY	
$I_{F(AV)}$	200 A
Type	Modules - Diode, High Voltage

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUE	UNITS
$I_{F(AV)}$		200	A
	$T_C$	100	°C
$I_{F(RMS)}$		314	A
$I_{FSM}$	50 Hz	8000	
	60 Hz	8376	
$I^2t$	50 Hz	320	kA <sup>2</sup> s
	60 Hz	291	
$I^2\sqrt{t}$		3200	kA <sup>2</sup> $\sqrt{s}$
$V_{RRM}$		400 to 1600	V
$T_J$	Range	-40 to 150	°C

### ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA
NKD200 NKJ200 NKC200	04	400	500	12
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNITS
Maximum average on-state current at case temperature	I <sub>F(AV)</sub>	180° conduction, half sine wave		200	A
				100	°C
Maximum RMS on-state current	I <sub>F(RMS)</sub>	180° conduction, half sine wave, 50Hz, T <sub>C</sub> = 100°C		314	A
Maximum peak, one-cycle, on-state non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	No voltage reappplied	8000	
		t = 8.3 ms		8376	
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	t = 10 ms	Sine half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	320	kA <sup>2</sup> s
		t = 8.3 ms		291	
		t = 10 ms	100% V <sub>RRM</sub> reappplied	224	
		t = 8.3 ms		204	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reappplied		3200	kA <sup>2</sup> √s
Maximum forward voltage drop	V <sub>FM</sub>	I <sub>FM</sub> = 600A, T <sub>J</sub> = 25 °C, 180° conduction		1.4	V

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub>	T <sub>J</sub> = 150 °C		12	mA
RMS isolation Voltage	V <sub>ISO</sub>	50 Hz, circuit to base, all terminals shorted, t = 1s		3000	V
		t = 60s		2500	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	$T_{Stg}, T_J$		- 40 to 150	°C
Maximum thermal resistance, junction to case per junction	$R_{thJC}$	DC operation	0.21	°C/W
Maximum thermal resistance, case to heatsink per module	$R_{thCS}$	Mounting surface, smooth, flat and greased	0.075	
Mounting torque $\pm 10\%$	IAP to heatsink, M6 busbar to IAP, M6	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.	4 to 6	N.m
Approximate weight			220	g
			7.8	oz.
Case style			New INT-A-PAK	

### ORDERING INFORMATION TABLE

Device code	<b>NKD</b>	<b>200</b>	<b>/</b>	<b>16</b>	<b>A</b>
	①	②	③	④	
①	- Module type: NKD, NKJ and NKC for (Diode + Diode) module				
②	- Current rating: $I_{F(AV)}$				
③	- Voltage code x 100 = $V_{RRM}$				
④	- Assembly type, "A" for soldering type				

Fig.1 On-state current vs. voltage characteristic

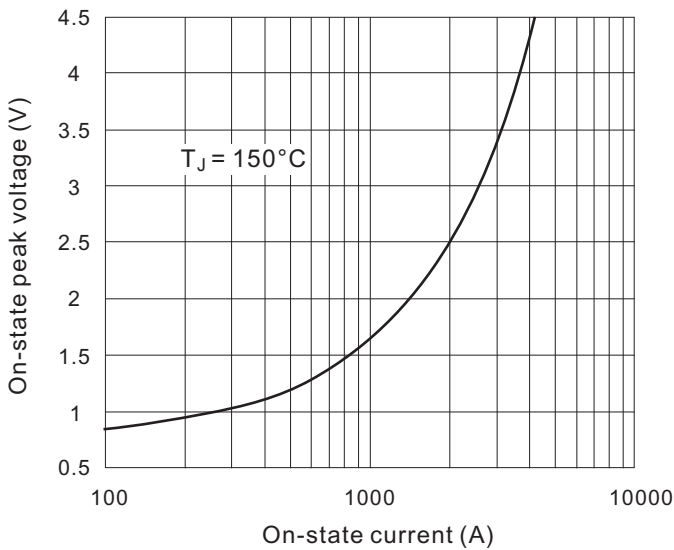


Fig.2 Transient thermal impedance(junction-case)

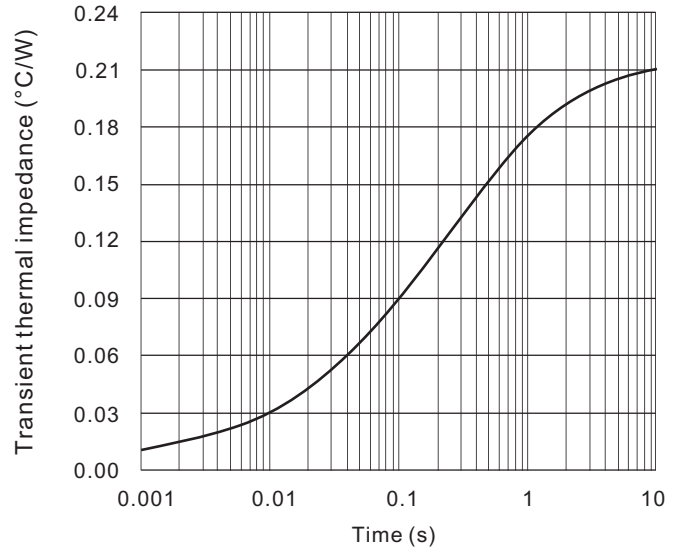


Fig.3 Power consumption vs. average current

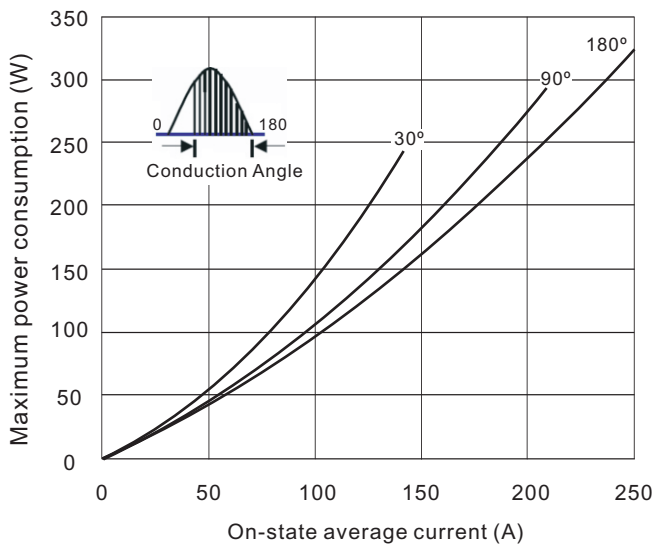


Fig.4 Case temperature vs. on-state average current

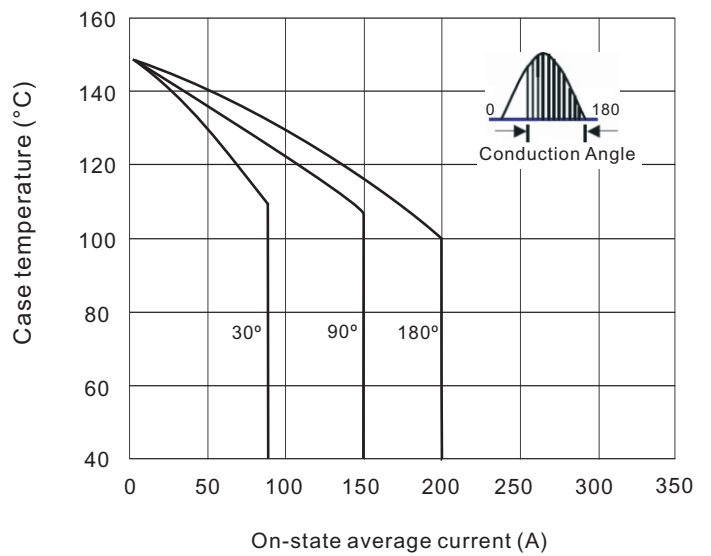


Fig.5 On-state surge current vs. cycles

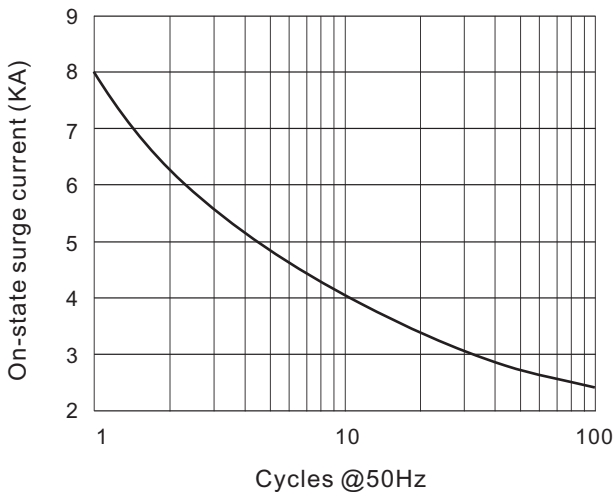


Fig.6  $I^2t$  Characteristic

